PATENT

#38 =A 3-29-cy

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of: Yasunori INOUE et al.

Serial Number: N t Yet Assigned

Filed: August 29, 1997

FABRICATION METHOD OF SEMICONDUCTOR DEVICE AND ABRASIVE

LIQUID USED THEREIN

## **CLAIM FOR PRIORITY UNDER 35 U.S.C. 119**

Assistant Commissioner for Patents Washington, D.C. 20231

August 29, 1997

Sir:

For:

The benefit of the filing dates of the following prior foreign applications are hereby requested for the above-identified application, and the priority provided in 35 U.S.C. 119 is hereby claimed:

Japanese Appln. No. 8-230826, filed on August 30, 1996; and Japanese Appln. No. 9-010426, filed on January 23, 1997.

In support of this claim, the requisite certified copies of said original foreign applications are filed herewith.

It is requested that the file of this application be marked to indicate that the applicants have complied with the requirements of 35 U.S.C. 119 and that the Patent and Trademark Office kindly acknowledge receipt of said documents.

In the event that any fees are due in connection with this paper, please charge our Deposit Account No. 01-2340.

Respectfully submitted,

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## 本国特許庁

PATENT OFFICE
JAPANESE GOVERNMENT

別紙添付の書類に記載されている事項は下記の出願書類に記載されて る事項と同一であることを証明する。

This is to certify that the annexed is a true copy of the following application as filed in this Office.

以頭年月日 hte of Application:

1996年 8月30日 August 30, 1996

類番号 plication Number:

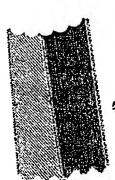
平成 8年特許顯第230826号

Pat. Appln. No. 8-230826

顧人 licant (s):

三洋電機株式会社

Sanyo Electric Co., Ltd.



1997年 5月30日

May 30, 1997

特 許 庁 長 官 Commissioner, Patent Office



Hisamitsu ARAI

出証番号 出証特平09-3039955

Shutsu-sho-No. Shutsu-sho-toku-hei 09-3039955

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